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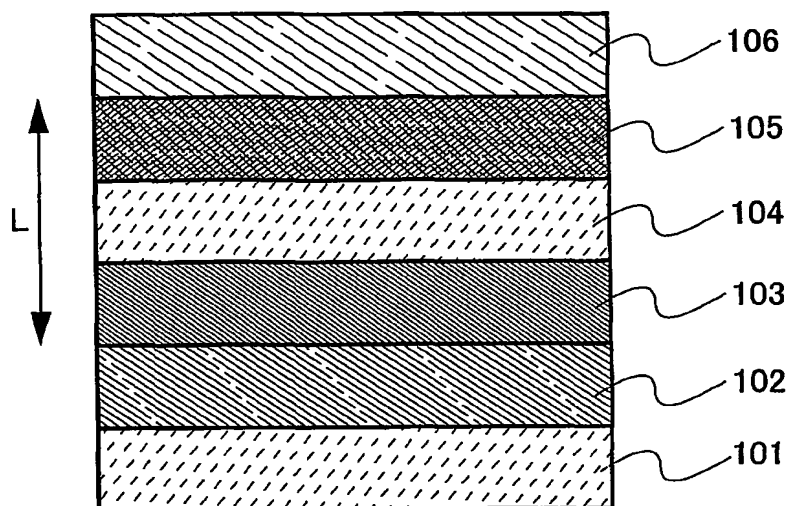
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(54) Title: LIGHT-EMITTING ELEMENT AND LIGHT-EMITTING DEVICE



(57) Abstract: It is an object of
the present invention to provide
a light-emitting element having a
layer containing a light-emitting
material and a transparent conductive
film between a pair of electrodes,
in which electric erosion of the
transparent conductive film and
metal can be prevented, and also
to provide a light-emitting device
using the light-emitting element.
According to one feature of the
invention, a light-emitting element
includes a first layer 102 containing
a light-emitting material, a second
layer 103 containing a material
having a donor level, a third layer 104
including a transparent conductive
film, and a fourth layer 105 containing
a hole-transporting medium between
a first electrode 101 and a second
electrode 106, in which the first layer
102, the second layer 103, the third
layer 104, the fourth layer 105, and the

second electrode 106 are provided sequentially, in which the second electrode 106 has a layer containing metal.

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